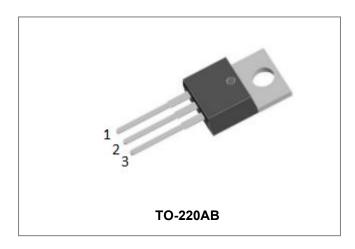






# MBR4080/90/100CT SCHOTTKY RECTIFIER



#### Features

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



# **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

# Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>		80	MBR4080CT	
Working Peak Reverse Voltage	$V_{RWM}$	-	90	MBR4090CT	V
DC Blocking Voltage	$V_R$		100	MBR40100CT	
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=115°C	20(Per Leg)		A
Average Nectilled Forward Current	IF (AV)	10-119 0	40(Per Device)		
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	250		Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	$V_{F1}$	@ 20A, Pulse, T <sub>J</sub> = 25 °C	0.80	0.88	V
	$V_{F2}$	@ 20A, Pulse, T <sub>J</sub> = 125 °C	0.70	0.74	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R}, T_J = 25  ^{\circ}\text{C}$	0.01	1.0	mA
	$I_{R2}$	$@V_R = \text{rated } V_R, T_J = 125  ^{\circ}\text{C}$	8	20	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	400	800	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

Pulse width < 300 μs, duty cycle < 2%

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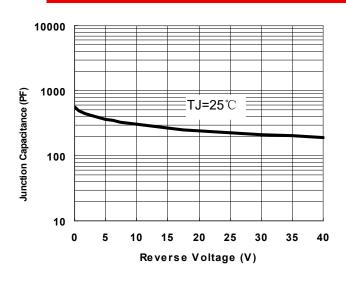




# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	2.0	°C/W
Approximate Weight	wt	-	2	g

## **Ratings and Characteristics Curves**



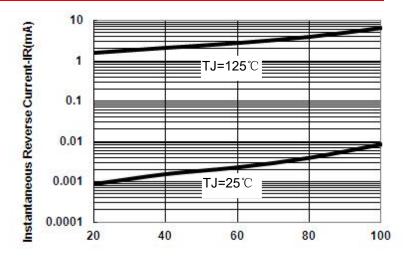


Fig.1-Typical Junction Capacitance

Percent of Rated Peak Reverse Voltage (%)

Fig.2-Typical Reverse Characteristics

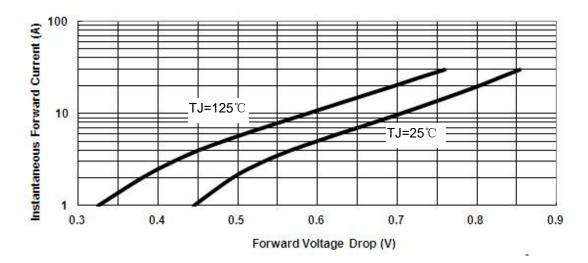


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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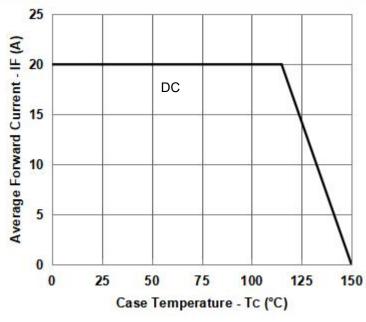
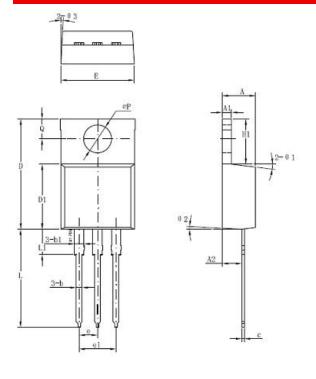


Fig.4 Forward Current Derating Curve

# **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters				
	Min	Typical	Max		
Α	3.56	-	4.83		
A1	0.51	-	1.4		
A2	2.03	-	2.92		
b	0.38	-	1.02		
b1	1.14	-	1.78		
С	0.31	-	0.61		
D	14.22	-	16.51		
D1	8.38	-	9.42		
E	9.65	-	10.67		
е	-	2.54	-		
e1	-	5.08	-		
H1	5.84	-	6.86		
L	12.7	-	14.73		
L1	-	-	6.35		
ФР	-	3.56	-		
Q	2.54	-	3.43		

<sup>•</sup> China - Germany - Korea - Singapore - United States •

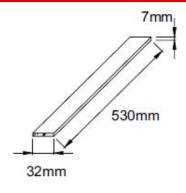
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### **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 40 = Forward Current (40A) 100 = Reverse Voltage(100V)

CT = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
MBR4080/90/100CT	TO-220AB (Pb-Free)	50 pcs/ tube	

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